



# TSA1036D

## General Purpose Dual PNP Transistor

SOT-363



Pin assignment:

- |                |                |
|----------------|----------------|
| 1. Emitter 1   | 6. Collector 1 |
| 2. Base 1      | 5. Base 2      |
| 3. Collector 2 | 4. Emitter 2   |

$BV_{CEO} = -32V$

$I_C = -500mA$

$V_{CE(SAT)} = 0.4V(\text{typ.}) @ I_C / I_B = 300mA / 30mA$

### Features

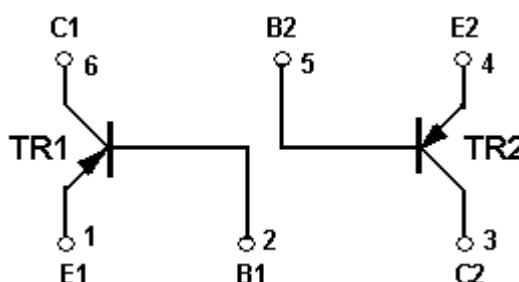
- Two TSA1036 chips in a SOT-363 package
- Transistor elements are independent, eliminating interference
- Optimal for low voltage operation

### Structure

- Epitaxial planar type.
- Mounting possible with SOT-323 automatic mounting machines.
- Complementary to TSC2411DCU6

### Ordering Information

Part No.	Packing	Package	Marking
TSA1036DCU6	3kpcs / reel	SOT-363	1PR



### Absolute Maximum Rating (Ta = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	$V_{CBO}$	-40V	V
Collector-Emitter Voltage	$V_{CEO}$	-32V	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Collector Current	$I_C$	-0.5	A
Collector Power Dissipation (note)	$P_D$	200 (total)	mW
Operating Junction Temperature	$T_J$	+150	°C
Operating Junction and Storage Temperature Range	$T_{STG}$	-55 to +150	°C

Note: 1. 150mW per element must not be exceeded.

### Electrical Characteristics (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Collector-Base Voltage	$I_C = -100\mu A, I_E = 0$	$BV_{CBO}$	-40	--	--	V
Collector-Emitter Breakdown Voltage	$I_C = -1mA, I_B = 0$	$BV_{CEO}$	-32	--	--	V
Emitter-Base Breakdown Voltage	$I_E = -100\mu A, I_C = 0$	$BV_{EBO}$	-6	--	--	V
Collector Cutoff Current	$V_{CB} = -20V, I_E = 0$	$I_{CBO}$	--	--	-0.5	$\mu A$
Emitter Cutoff Current	$V_{EB} = -4V, I_C = 0$	$I_{EBO}$	--	--	-0.5	$\mu A$
Collector-Emitter Saturation Voltage	$I_C / I_B = -100mA / -10mA$	$V_{CE(SAT)1}$	--	--	-0.4	V
Collector-Emitter Saturation Voltage	$I_C / I_B = -300mA / -30mA$	$V_{CE(SAT)2}$	--	-0.40	-0.75	V
DC Current Transfer Ratio	$V_{CE} = -3V, I_C = 100mA$	$h_{FE}$	120	--	390	
Transition Frequency	$V_{CE} = -10V, I_C = -1mA, f=100MHz$	$f_T$	--	180	--	MHz
Output Capacitance	$V_{CB} = -10V, f=1MHz$	$C_{ob}$	--	2	--	pF

Note : pulse test: pulse width  $\leq 380\mu s$ , duty cycle  $\leq 2\%$

## Electrical Characteristics Curve

Figure 1. Current Gain vs Collector Current

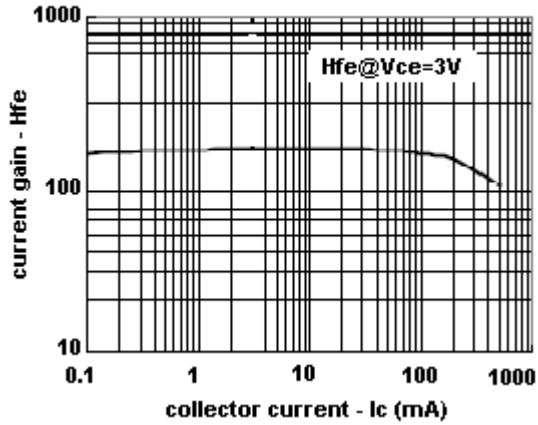


Figure 2. Saturation Voltage vs Collector Current

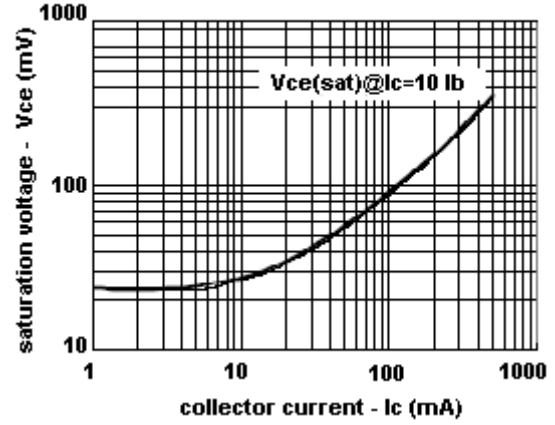


Figure 3. Saturation Voltage vs Collector Current

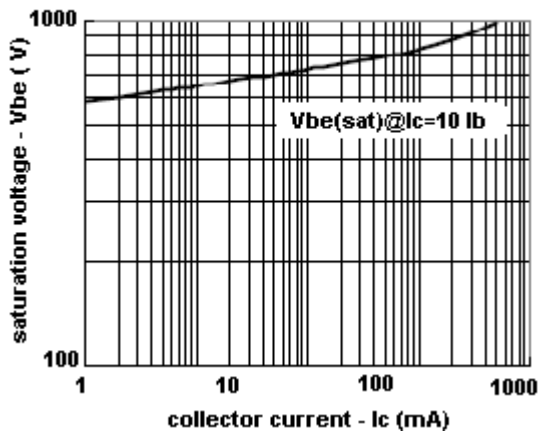


Figure 4. Power Derating Curves

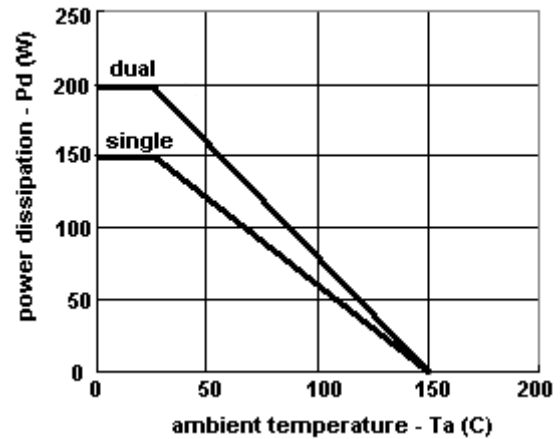
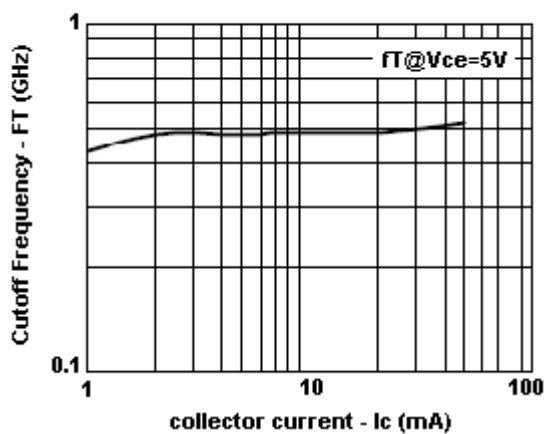
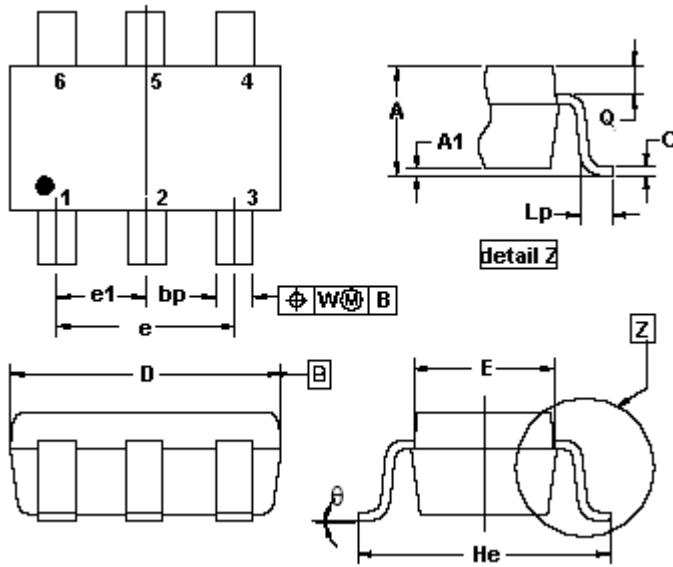


Figure 5. Cutoff Frequency vs Collector Current



## SOT-363 Mechanical Drawing



SOT-363 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.10	0.031	0.043
A1	--	0.10	--	0.004
bp	0.10	0.30	0.004	0.012
C	0.10	0.25	0.004	0.010
D	1.80	2.20	0.071	0.087
E	1.15	1.35	0.045	0.053
e	1.30 (typ)		0.052 (typ)	
e1	0.65 (typ)		0.026 (typ)	
He	2.00	2.20	0.079	0.087
Lp	0.10	0.3	0.004	0.012
Q	0.20 (typ)		0.008 (typ)	
W	0.20 (typ)		0.008 (typ)	
$\theta$	10° (typ)		10° (typ)	